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Typical Applications

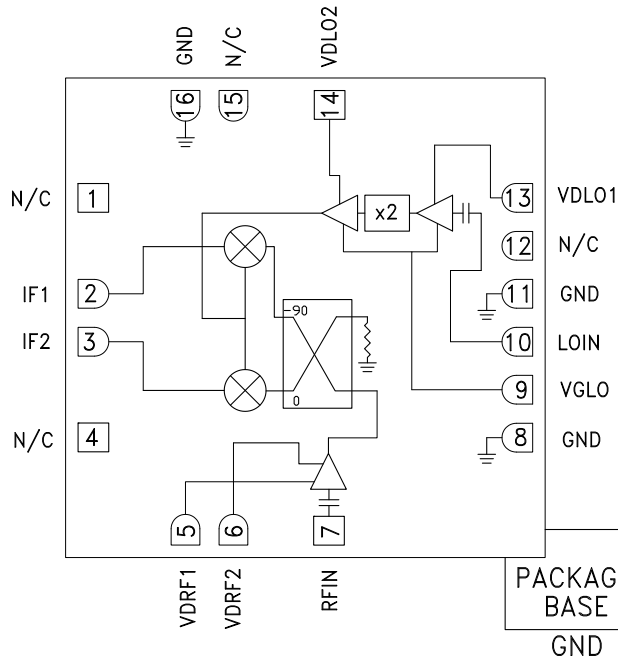
The HMC6147ALC5A is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Features

- Conversion Gain: 13 dB
- Excellent Image Rejection: 25 dB
- Output IP3: +12 dBm
- 16 Lead 5x5 mm SMT Ceramic Package: 25 mm²

Functional Diagram



General Description

The HMC6147ALC5A is a compact GaAs MMIC I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 13 dB with 25 dBc of sideband rejection. The HMC6147ALC5A utilizes a low noise amplifier to drive the I/Q mixer where the LO is driven by a X2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC6147ALC5A is a much smaller alternative to hybrid style single sideband converter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications ^{[1][2]}, $T_A = +25^\circ\text{C}$, $IF = 1000\text{ MHz}$,
 $LO = +3\text{ dBm}$, $VDLO1,2 = +3V$, $IDLO1,2 = 150\text{ mA}$, $VDRF1,2 = +3V$, $IDRF1,2 = 75\text{ mA}$, USB ^{[1][2]}

Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF		37 - 44		GHz
Frequency Range, LO		16.5 - 22		GHz
Frequency Range, IF		0 - 4		GHz
Conversion Gain	10	13		dB
Image Rejection	15	25		dBc
1 dB Compression (Output)		1		dBm
IP3 (Input)		2		dBm
Noise Figure		3.5		dB
Supply Current IDLO1 + IDLO2 quiescent ^[2]		150		mA
Supply Current IDRF1 + IDRF2		75		mA

[1] Unless otherwise noted all measurements performed with low side LO, IF = 1000 MHz and external IF 90° hybrid.

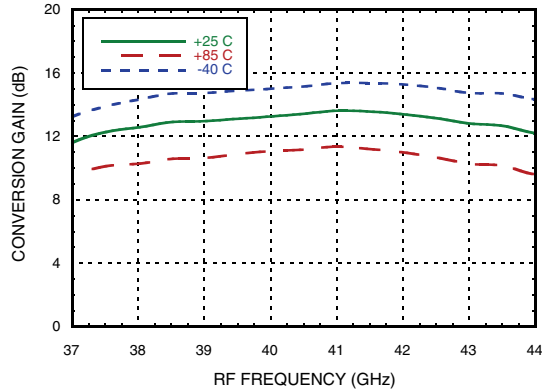
[2] Adjust Vgg between -2 to 0V to achieve IDLO1 + IDLO2 = 150 mA Typical with RF turned off.



**GaAs MMIC I/Q DOWNCONVERTER
37 - 44 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

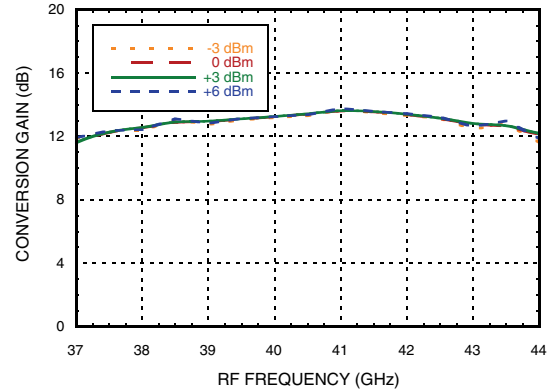
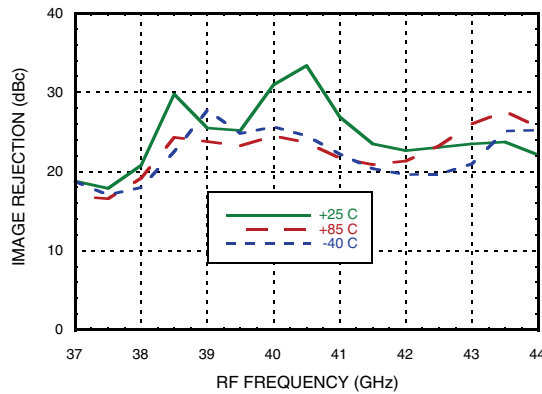
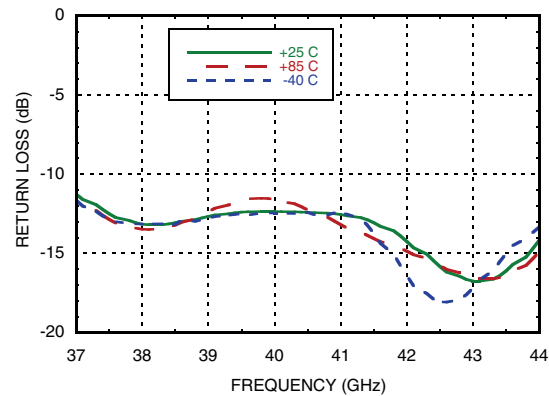


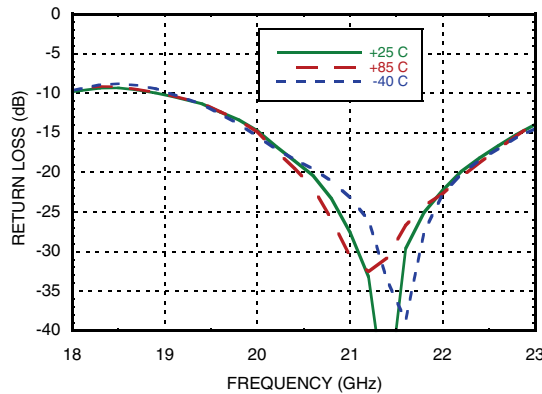
Image Rejection vs. Temperature



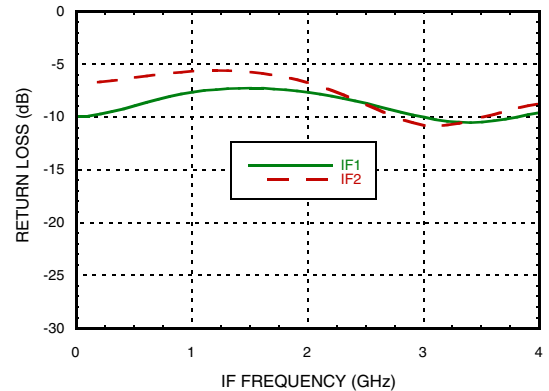
RF Return Loss



LO Return Loss vs. Temperature



IF Return Loss [1]



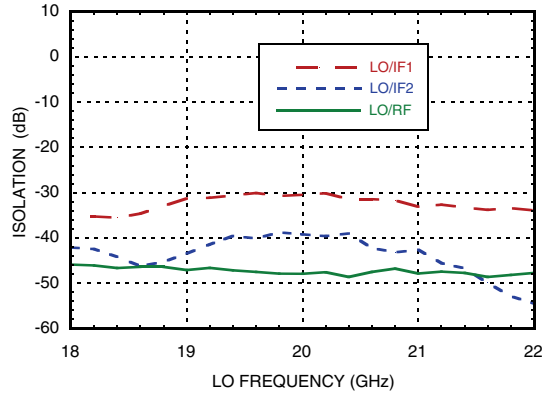
[1] Data taken without external IF 90° hybrid



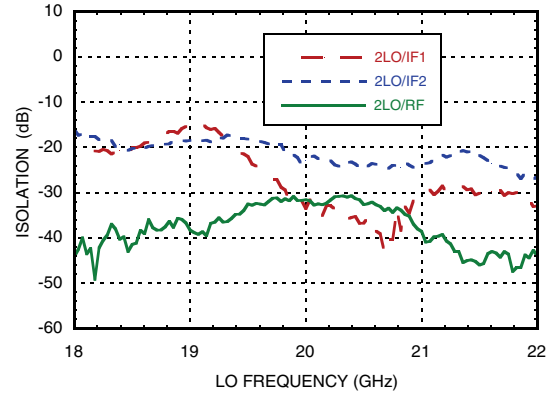
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

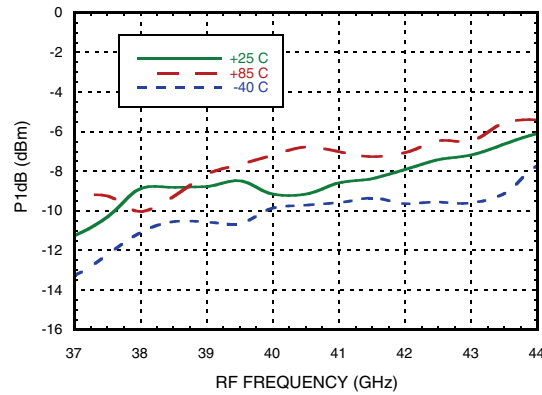
LO Isolation



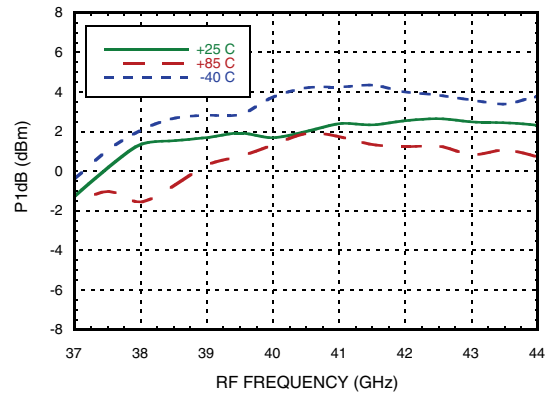
2LO Isolation



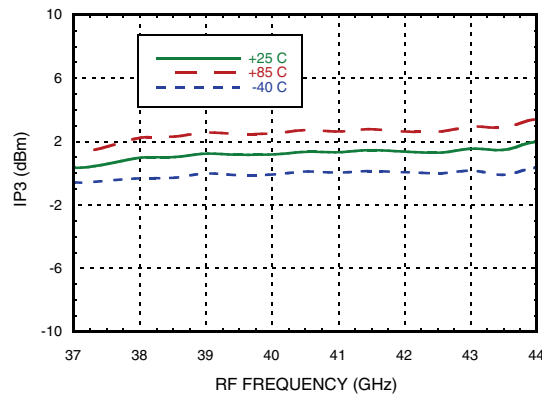
Input P1dB, USB vs. Temperature



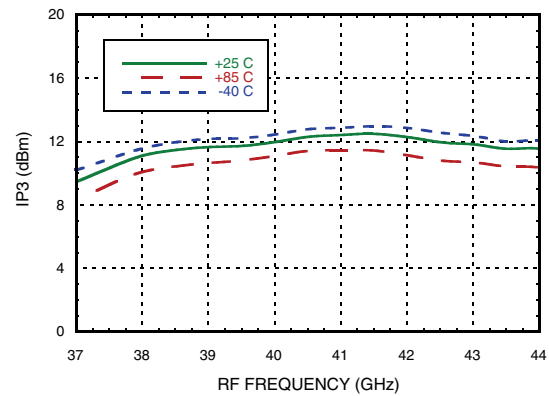
Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



Output IP3, USB vs. Temperature

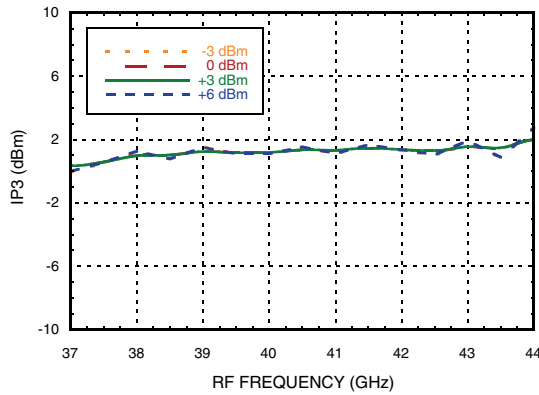




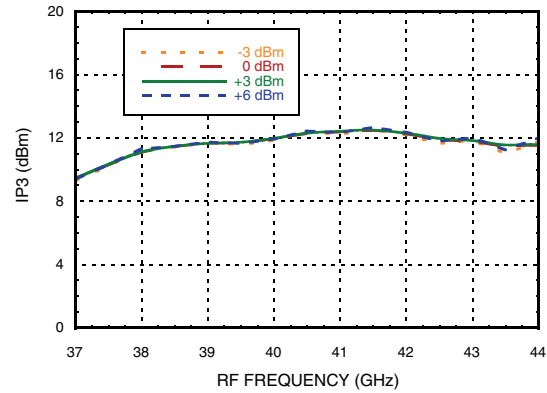
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

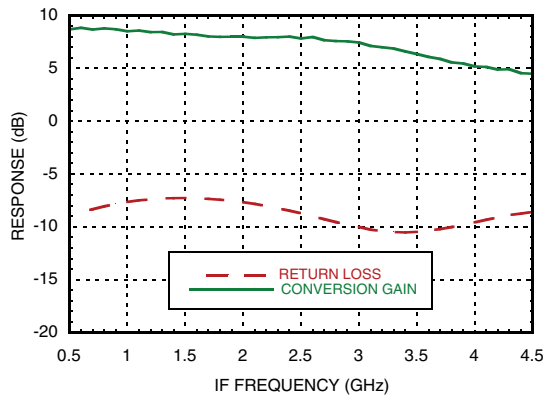
Input IP3, USB vs. LO Power



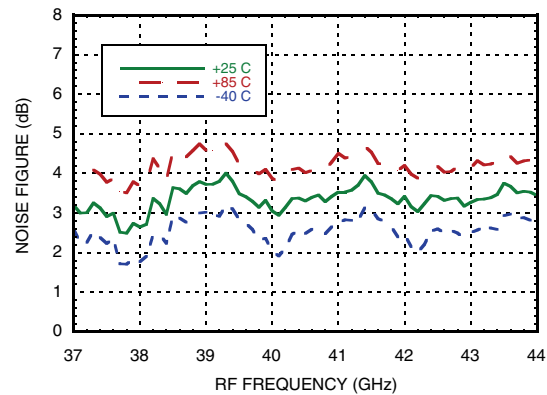
Output IP3, USB vs. LO Power



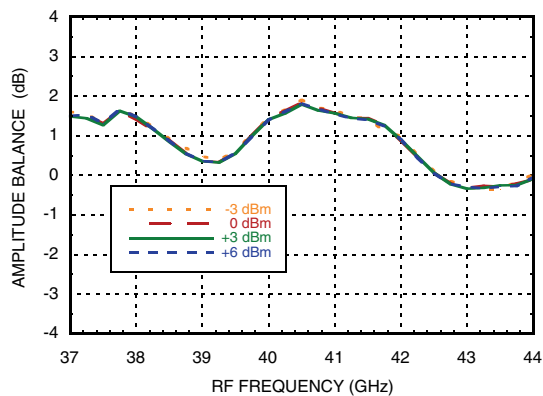
IF Bandwidth [1]



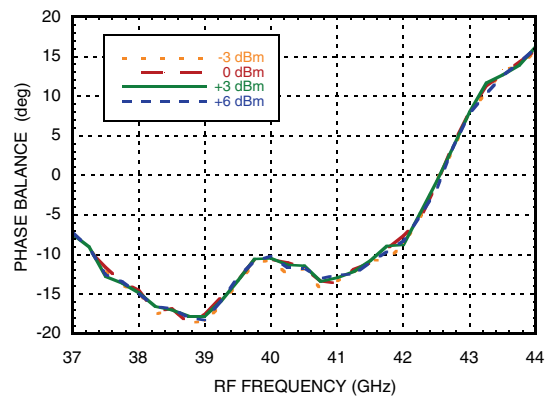
Noise Figure vs. Temperature



Amplitude Balance vs. LO Drive



Phase Balance vs. LO Drive



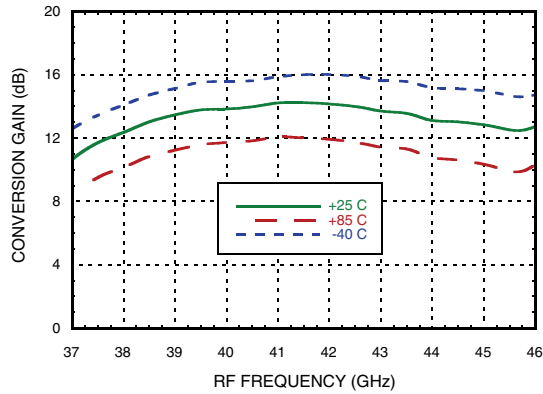
[1] LO = 18GHz



GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

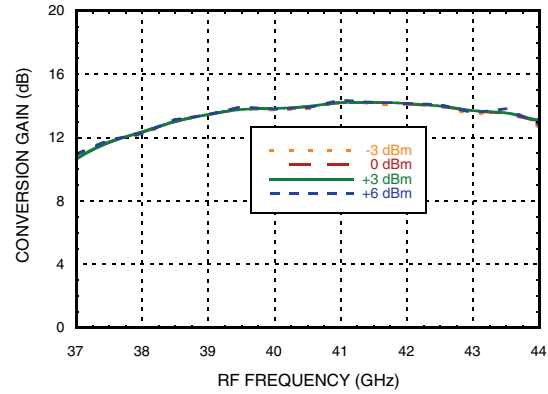
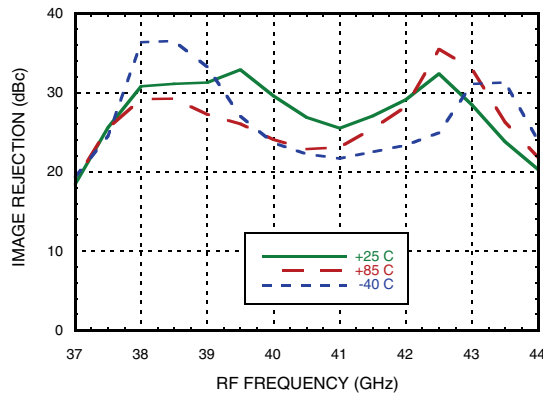
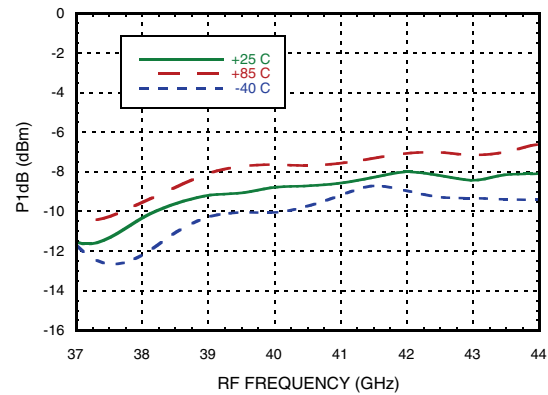


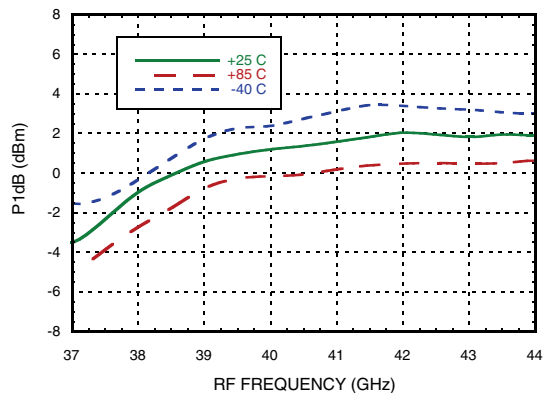
Image Rejection vs. Temperature



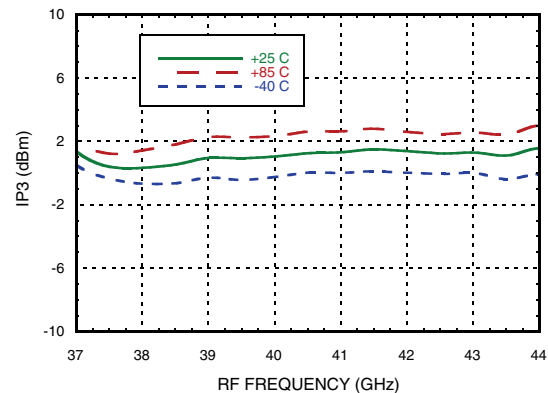
Input P1dB, USB vs. Temperature



Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature

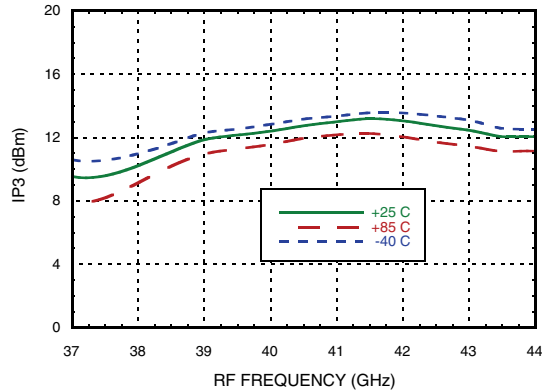




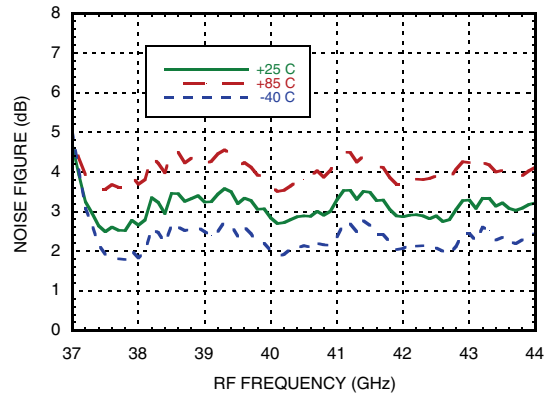
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Output IP3, USB vs. Temperature



Noise Figure vs. Temperature



MxN Spurious Outputs [1][2]

mRF	nLO				
	0	1	2	3	4
0	xx	38	21		
1	17	48	0		
2	xx	xx	47		
3					
4					
5					

RF = 40 GHz @ -8 dBm
LO = 19.5 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

mRF	nLO				
	0	1	2	3	4
0	xx	42	16		
1	17	47	0		
2	xx	xx	43		
3					
4					
5					

RF = 40 GHz @ -8 dBm
LO = 19.0 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

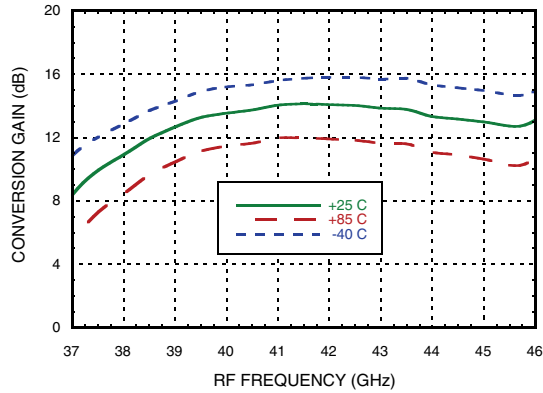
mRF	nLO				
	0	1	2	3	4
0	xx	44	20		
1	17	41	0		
2	xx	xx	50		
3					
4					
5					

RF = 40 GHz @ -8 dBm
LO = 18.5 GHz @ +4 dBm

[1] Data taken without external IF 90° hybrid
[2] All values in dBc below RF power level (2LO + IF) USB

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

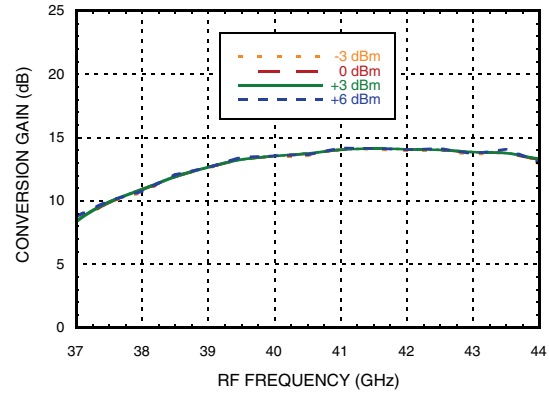
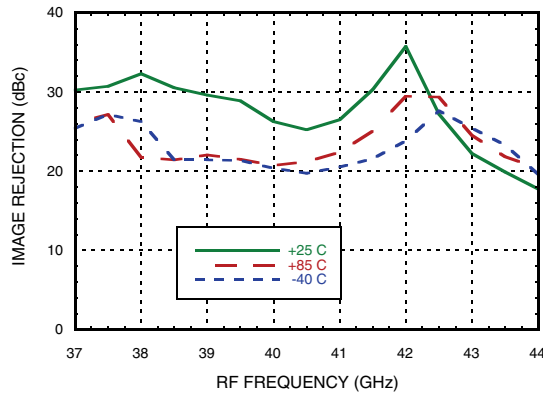
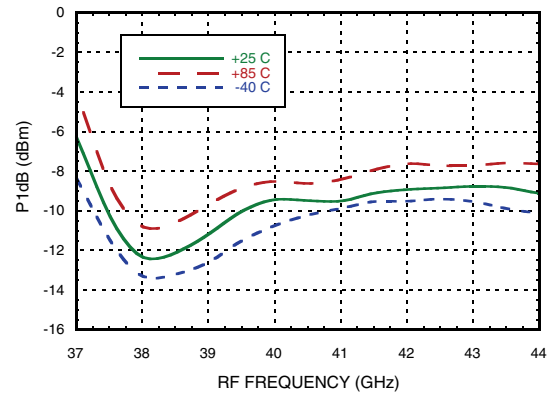


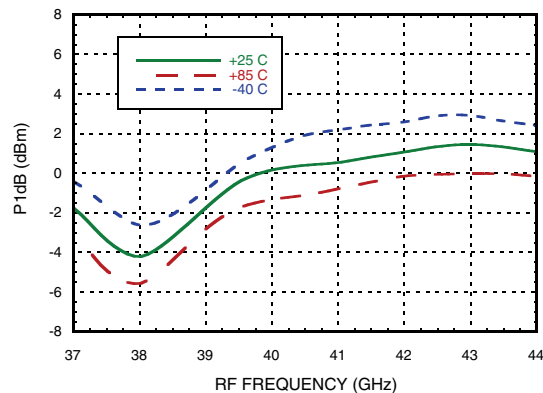
Image Rejection vs. Temperature



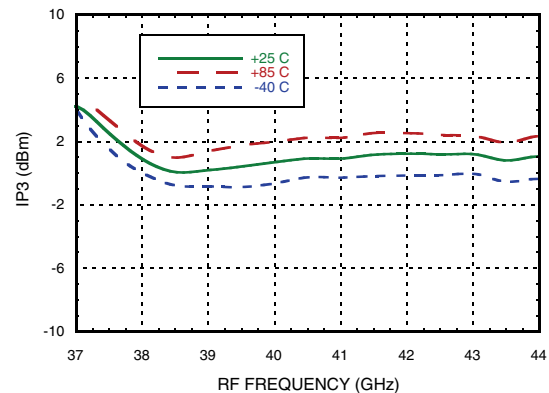
Input P1dB, USB vs. Temperature



Output P1dB, USB vs. Temperature

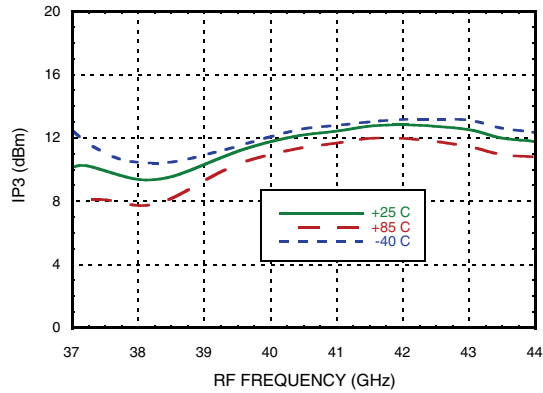
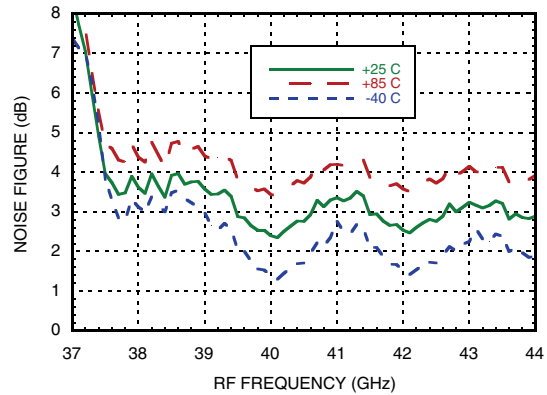


Input IP3, USB vs. Temperature





Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

Output IP3, USB vs. Temperature

Noise Figure vs. Temperature




GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

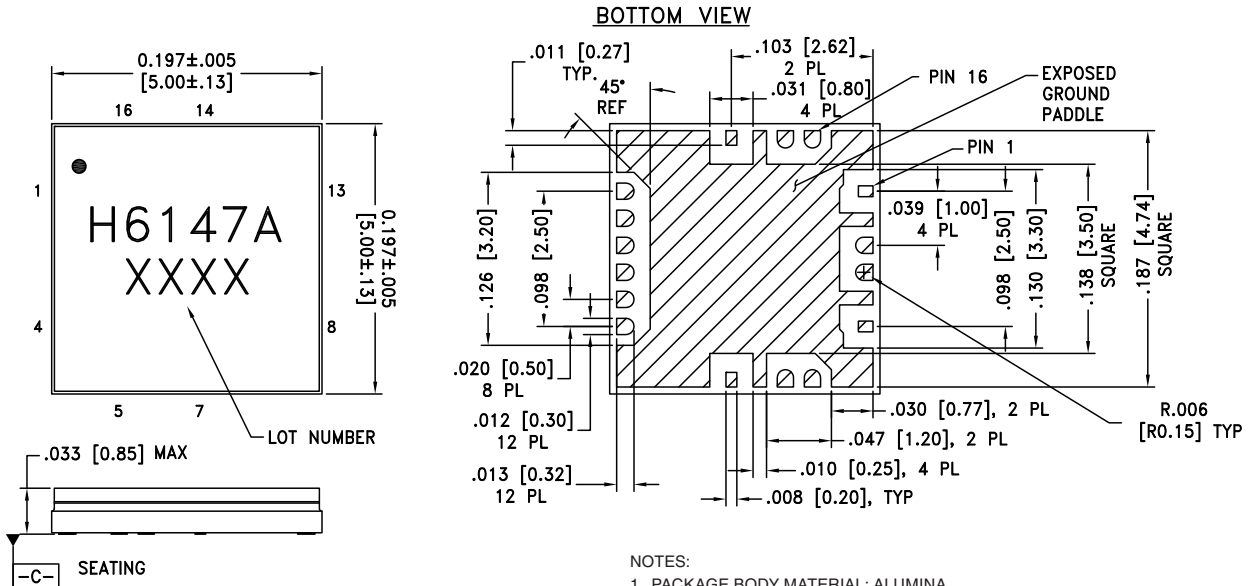
Absolute Maximum Ratings

RF Input	+8 dBm
LO Input	+10 dBm
Bias Voltage, VDLO and VDRF	+3.5V
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 17.8 mW/°C above 85°C)	1.6 W
Thermal Resistance (channel to ground paddle)	56 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



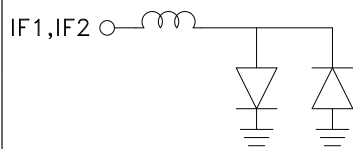
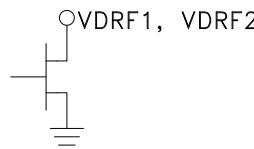
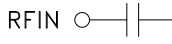

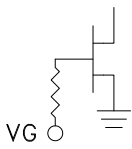
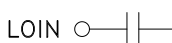
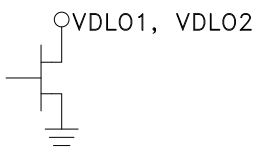
Package Information

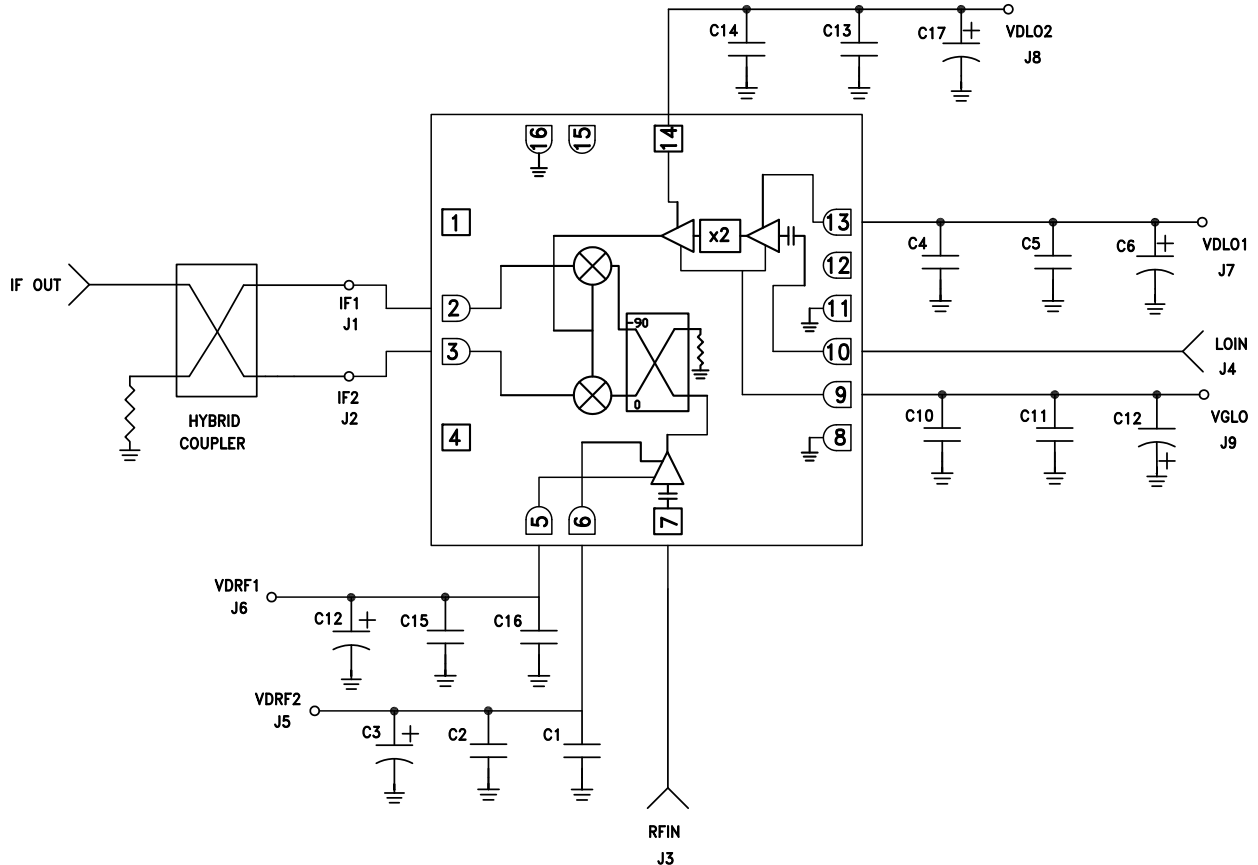
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC6147ALC5A	Alumina, White	Gold over Nickel	MSL3 ^[1]	6147A XXXX

[1] Max peak reflow temperature of 260 °C

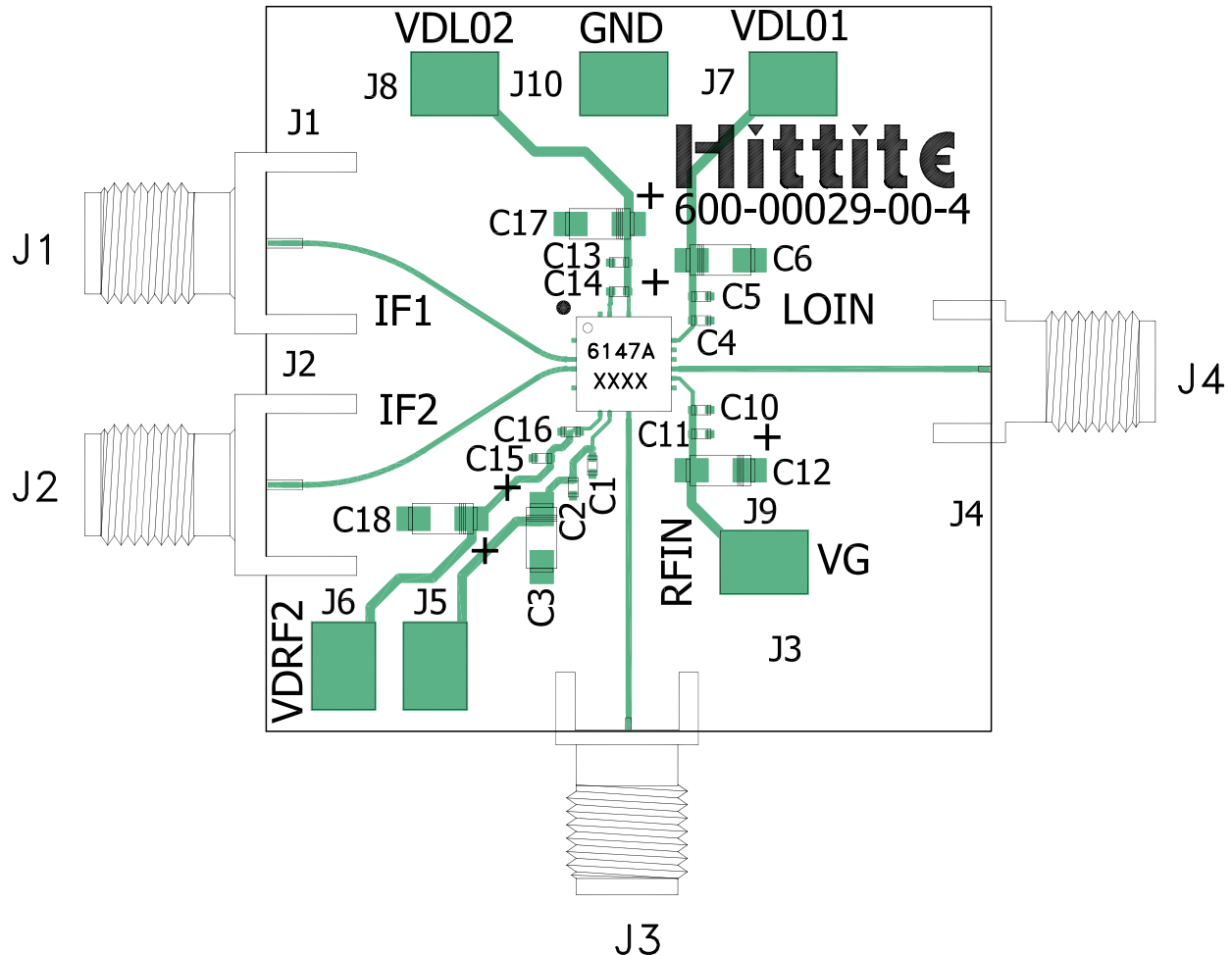
[2] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 12,15	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	IF1	These pins are DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	
3	IF2		
5	VDRF1	Bias for LNA. The recommended DC voltage is 3V	
6	VDRF2		
7	RFIN	This pin is AC coupled and matched to 50 Ohms.	
8,11, 16	GND	These pins and exposed ground paddle must be connected to RF/DC ground.	
9	VG	Adjust VGLO for -1V to 0V to set the multiplier quiescent current to 150mA	
10	LOIN	LO Input Port. The recommended LO Power is 0 to 6 dBm	
13	VDLO1	Bias for Multiplier input Buffer Amp. The recommended DC voltage is 3V	
14	VDLO2	Bias for Multiplier output Buffer Amp. The recommended DC voltage is 3V	

Typical Application


C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C19	4.7 μ F Capacitor, Case A Pkg.

Evaluation PCB

List of Materials for Evaluation PCB Eval01-HMC6147ALC5A ^[1]

Item	Description
J1, J2	SMA Connector
J3, J4	K-Connector SRI
J5 - J10	DC Pins
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C18	4.7 uF Capacitor, Case A
U1	HMC6147ALC5A Downconverter
PCB [2]	600-00029-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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